

# **isc** Silicon NPN Power Transistor

# 2SC2922

### **DESCRIPTION**

- High Collector-Emitter Breakdown Voltage-V<sub>(BR)CEO</sub>= 180V(Min)
- Good Linearity of h<sub>FE</sub>
- · Complement to Type 2SA1216
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

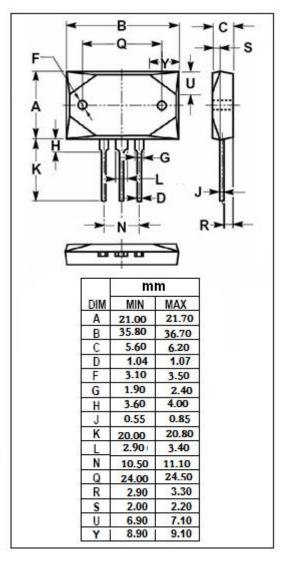
# PIN 1. BASE 2. COLLECTOR 3. BMITTER 1 2 3 MT-200 package

### **APPLICATIONS**

• Designed for audio and general purpose applications.

# ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>CBO</sub>	Collector-Base Voltage	180	V
Vceo	Collector-Emitter Voltage	180	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
lc	Collector Current-Continuous	17	A
I <sub>B</sub>	Base Current-Continuous	5	А
Pc	Pc Collector Power Dissipation @ Tc=25°C		W
TJ	T <sub>J</sub> Junction Temperature		°C
T <sub>stg</sub> Storage Temperature Range		-55~150	°C





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# **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

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SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT		
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	Ic= 25mA ; I <sub>B</sub> = 0	180			V		
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 8A; I <sub>B</sub> = 0.8A			2.0	V		
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 180V; I <sub>E</sub> = 0			100	μА		
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 5V; I <sub>C</sub> =0			100	μА		
h <sub>FE</sub>	DC Current Gain	Ic= 8A; V <sub>CE</sub> = 4V	30		180			
Сов	Output Capacitance	I <sub>E</sub> = 0; V <sub>CB</sub> = 10V;f <sub>test</sub> = 1.0MHz		250		pF		
f <sub>T</sub>	Current-Gain—Bandwidth Product	I <sub>E</sub> = -2A; V <sub>CE</sub> = 12V	10			MHz		
Switching times								
ton	Turn-on Time			0.2		μs		
t <sub>stg</sub>	Storage Time	$I_{C}$ = 10A ,R <sub>L</sub> = 4 $\Omega$ , $I_{B1}$ = - $I_{B2}$ = 1A, $V_{CC}$ = 40V		1.3		μS		
t <sub>f</sub>	Fall Time			0.45		μ <b>s</b>		

## ♦ h<sub>FE</sub> Classifications

0	Y	Р	G
30-60	50-100	70-140	90-180

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